TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (Ultra High speed U-MOSIII)

TPCP8003-H

High Efficiency DC / DC Converter Applications Notebook PC Applications Portable Equipment Applications

- Small footprint due to a small and thin package
- High speed switching
- Small gate charge: Q_{SW} = 7.5 nC (typ.)
- Low drain-source ON-resistance: $RDS(ON) = 130 \text{ m}\Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 5.4 \text{ S} (typ.)$
- Low leakage current: $I_{DSS} = 10 \ \mu A (max) (V_{DS} = 100V)$
- Enhancement mode: V_{th} = 1.1 to 2.3 V (V_{DS} = 10 V, I_D = 1mA)

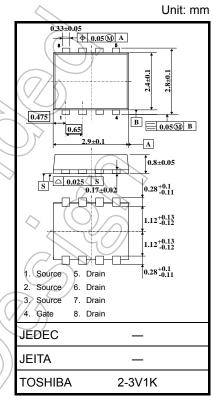
Absolute Maximum Ratings (Ta = 25°C)

				-
Characteristic		Symbol	Rating	○ Unit
Drain-source voltage		V _{DSS}	100	V
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V _{DGR}	100	V
Gate-source voltage		V _{GSS}	±20	(v)
Drain current	DC (Note 1)	ID	2.2	A
	Pulsed (Note 1)	DP	8.8	
Drain power dissipation (t = 5 s) (Note 2a)		PD	1.68	W
Drain power dissipation (t = 5 s) (Note 2b)		PD	0.84	w
Single-pulse avalanche energy (Note 3)		EAS	3.93	mJ
Avalanche current		I _{AR}	2.2	А
Repetitive avalanche energy (Tc=25°C) (Note 4)		Ear	0.016	mJ
Channel temperature		Tch	150	°C
Storage temperature range		Tstg	–55 to 150	°C

Note: For Notes 1 to 4, refer to the next page.

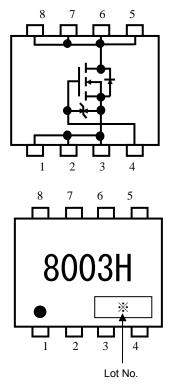
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.017 g (typ.)

Circuit Configuration

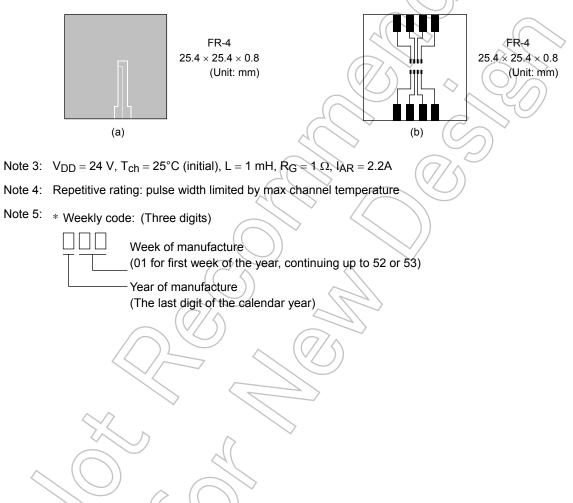


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Thermal Characteristics

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to ambient $(t = 5 s)$ (Note 2a)	R _{th (ch-a)}	74.4	°C/W
Thermal resistance, channel to ambient $(t = 5 s)$ (Note 2b)	R _{th (ch-a)}	148.8	°C/W

- Note 1: The channel temperature should not exceed 150°C during use.
- Note 2: (a) Device mounted on a glass-epoxy board (a)
- (b) Device mounted on a glass-epoxy board (b)



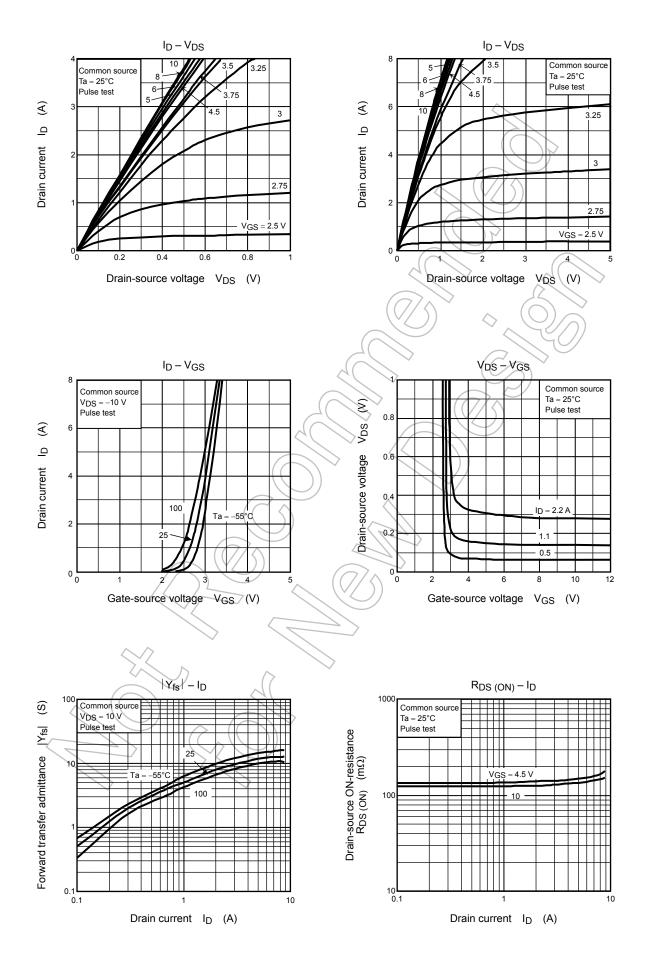
Electrical Characteristics (Ta = 25°C)

Ch	aracteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I _{GSS}	$V_{GS}=\pm 16~V,~V_{DS}=0~V$	_		±10	μA
Drain cutoff curre	ent	I _{DSS}	$V_{DS} = 100 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_		10	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	100	_	_	v
		V (BR) DSX	$I_D = 10$ mA, $V_{GS} = -20$ V	60	1	_	v
Gate threshold vo	oltage	V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	h)/	2.3	V
Drain-source ON-resistance		Pro (out)	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 1.1 \text{ A}$	77	140	190	mΩ
		R _{DS (ON)}	V _{GS} = 10 V, I _D = 1.1 A	Ĥ	130	180	
Forward transfer	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 1.1 A	2.7	5.4	_	S
Input capacitance	9	C _{iss}			360	_	
Reverse transfer	capacitance	C _{rss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	22	-	pF
Output capacitance		C _{oss}		_	75	\searrow	
Switching time	Rise time	tr	$10 V \square ID \neq 1.1 A$		7		
	Turn-on time	t _{on}	$V_{GS} = 10 V$ 0 V 0 V		14		ns
	Fall time	tf		$\widehat{\mathcal{P}}$	3		115
	Turn-off time	toff	$V_{DD} \simeq 50 \text{ V}$ Duty \leq 1%, $t_{W} =$ 10 μs) –	17		
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \simeq 80$ V, $V_{GS} = 10$ V, $I_D = 2.2$ A	_	7.5	_	
			$V_{DD} \simeq 80$ V, $V_{GS} = 5$ V, $I_D = 2.2$ A	_	4.5	_	
Gate-source cha	rge 1	Q _{gs1}		_	1.6	_	nC
Gate-drain ("Mille	er") charge	Qgd	$V_{DD}\simeq 80~V,~V_{GS}=10~V,~I_{D}=2.2~A$	_	1.3		
Gate switch char	ge	Qsw		_	2.0	_	

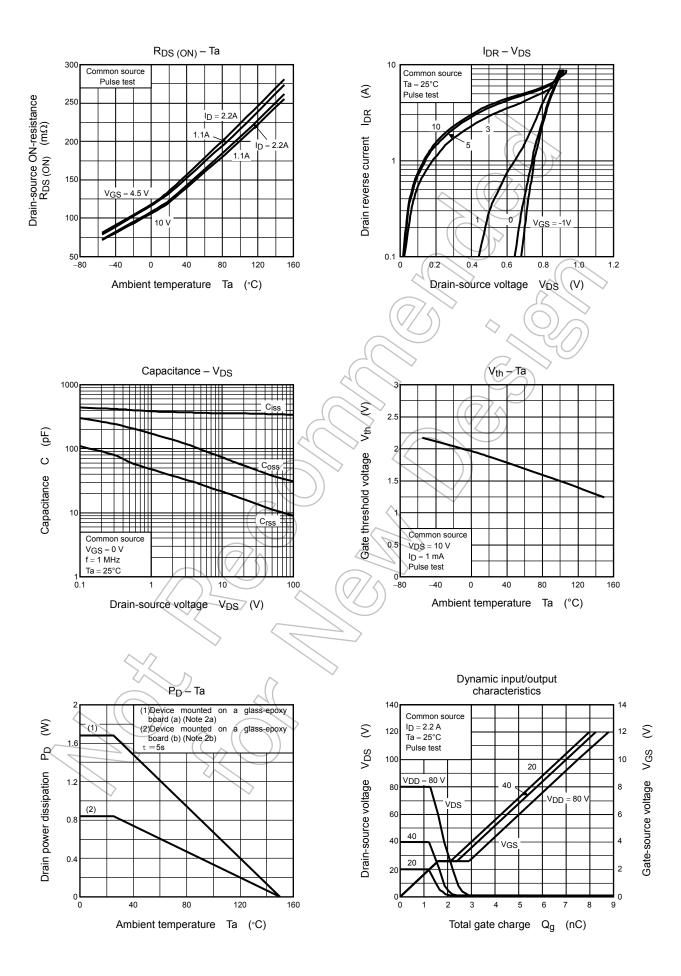
Source-Drain Ratings and Characteristics (Ta = 25°C)

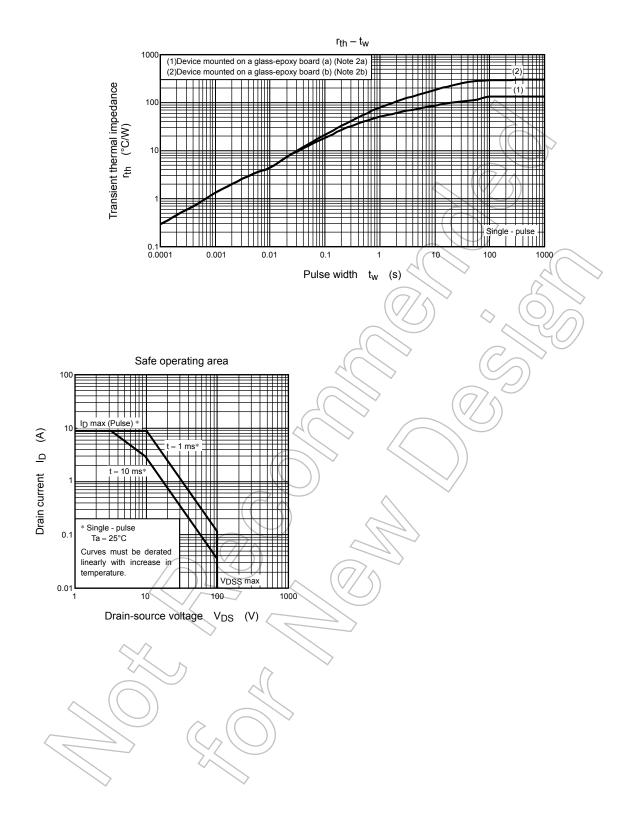
Characteristic	Symbol Test Condition	Min	Тур.	Max	Unit
Drain reverse current Pulse (Note 1)	IDRP -	_		8.8	Α
Forward voltage (diode)	V_{DSF} I_{DR} = 2.2 A, V_{GS} = 0 V	_		-1.2	V

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